

## **Bipolar Transistor**

# 100 V, 2.5 A, Low V<sub>CE(sat)</sub> NPN Single LFPAK

### **NSS1002CL**

This device is bipolar junction transistor featuring high current, low saturation voltage, and high speed switching.

Suitable for automotive applications. AEC-Q101 qualified and PPAP capable. (NSVS1002CLTWG)

#### **Features**

- Complement to NSS1001CL
- Large Current Capacitance
- Low Collector to Emitter Saturation Voltage
- Thin Profile LFPAK8 3.3 x 3.3 mm Package
- High-Speed Switching
- High Allowable Power Dissipation
- AEC-Q101 Qualified and PPAP Capable (NSVS1002CLTWG)
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Typical Applications**

- Load Switch
- Gate Driver Buffer
- DC-DC Converters

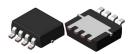
#### **Specifications**

#### **ABSOLUTE MAXIMUM RATING** at Ta = 25°C

Parameter	Symbol	Value	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>	120	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-to-Base Voltage	V <sub>EBO</sub>	6.5	V
Collector Current	I <sub>C</sub>	2.5	Α
Collector Current (Pulse)	I <sub>CP</sub>	4	Α
Collector Dissipation	P <sub>C</sub> (Note 1)	0.8	W
	P <sub>C</sub> (Note 2)	2.2	
Junction Temperature	TJ	175	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Mounted on FRB with minimum pad of Copper 2 oz
- 2. Mounted on FRB with 1 in/sq pad of Copper 2 oz



LFPAK8 3.3x3.3, 0.65P CASE 760AD

#### **ELECTRICAL CONNECTION**



#### MARKING DIAGRAM

NSS 1002G AWLYW

NSS1002 = Specific Device Code

A = Assembly Location

WL = Wafer Lot
Y = Year
W = Work Week
G = Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

#### **ELECTRICAL CHARACTERISTICS** at Ta = 25°C

				Value		
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	VCB = 120 V IE = 0 A			0.1	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	VEB = 6.5 V IC = 0 A			0.1	μА
DC Current Gain	h <sub>FE</sub>	VCE = 5 V IC = 100 mA	140		400	
Gain-Bandwidth Product	f <sub>T</sub>	VCE = 10 V IC = 100 mA		200		MHz
Output Capacitance	C <sub>ob</sub>	VCB = 10 V f = 1 MHz		12		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)1</sub>	IC = 100 mA IB = 10 mA		0.018	0.036	V
	V <sub>CE(sat)2</sub>	IC = 1 A IB = 100 mA		0.08	0.15	V
	V <sub>CE(sat)3</sub>	IC = 2.5 A IB = 250 mA		0.18	0.36	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	IC = 1 A IB = 100 mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	IC = 10 μA, IE = 0 A	120			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	IC = 1 mA, RBE = ∞	100			V
Emitter to Base Breakdown Voltage	V <sub>(BR)EBO</sub>	IE = 10 μA, IC = 0 A	6.5			V
Turn-On Time	t <sub>on</sub>	See Figure 1		15		ns
Storage Time	t <sub>stg</sub>			790		ns
Fall Time	t <sub>f</sub>			46		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

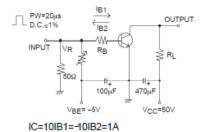
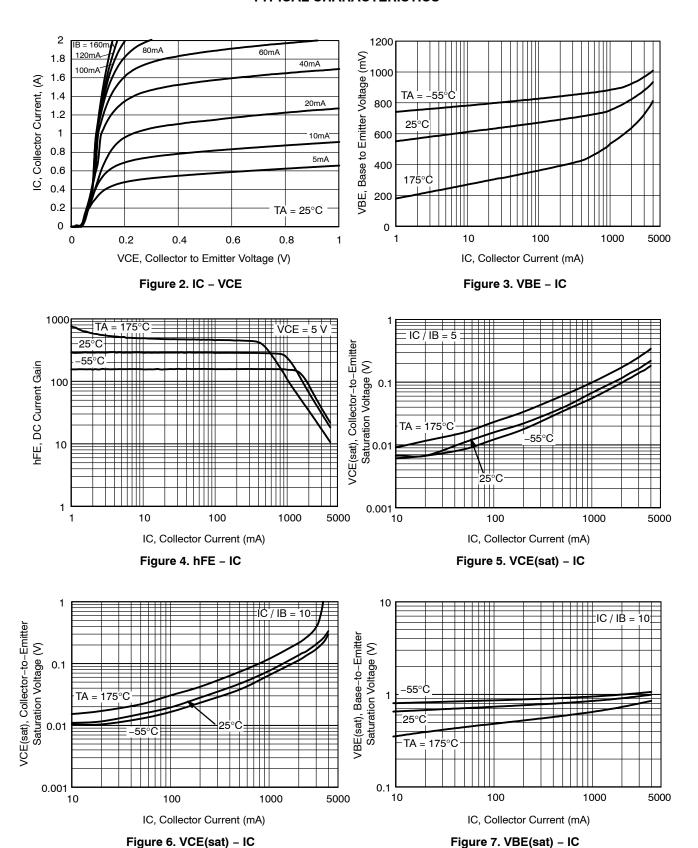


Figure 1. Switching Time Test Circuit

#### **ESD RATING**

Parameter	Symbol	Value	Unit	Class
Electrostatic Discharge - Human Body Model	НВМ	>2000, <4000	V	2
Electrostatic Discharge - Machine Model	MM	>400	V	M4

#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**

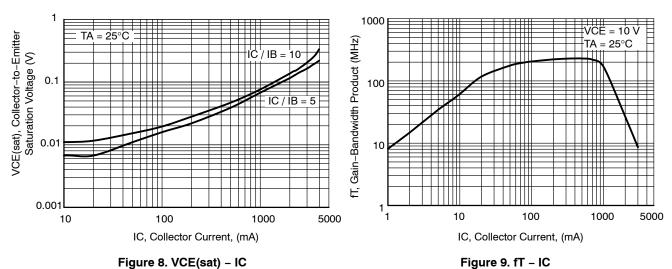


Figure 8. VCE(sat) - IC

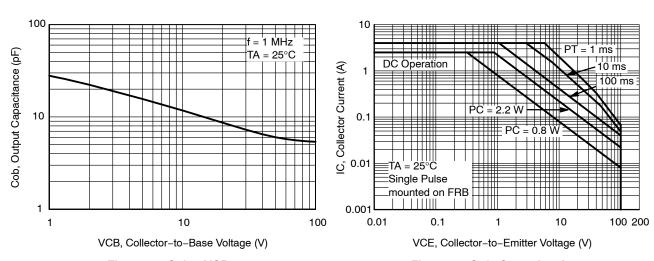


Figure 10. Cob - VCB

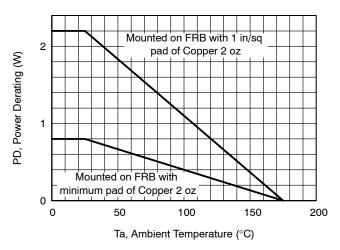


Figure 12. Power Derating

Figure 11. Safe Operating Area

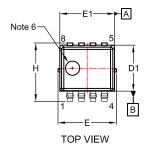
#### **ORDERING INFORMATION**

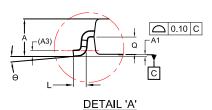
Device	Marking	Package	Shipping (Qty / Packing) <sup>†</sup>
NSVS1002CLTWG	NSS1002G	LFPAK8 (Pb-Free / Halogen Free)	3,000 / Tape & Reel
NSS1002CLTWG	NSS1002G	LFPAK8 (Pb-Free / Halogen Free)	3,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

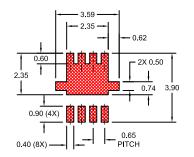








SCALE: 2:1

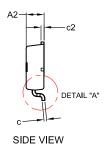


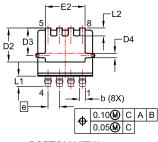
#### LAND PATTERN RECOMMENDATION

\*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

#### LFPAK8 3.3x3.3, 0.65P CASE 760AD ISSUE E

**DATE 16 NOV 2020** 





**BOTTOM VIEW** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS, MOLD FLASH, PROTRUSIONS OR BURRS SHALL NOT EXCEED 0.150mm PER SIDE.
- 4. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- DATUMS A AND B ARE DETERMINED AT DATUM PLANE H
- OPTIONAL MOLD FEATURE.

MID	MILLIMETERS			
JIW.	MIN.	NOM.	MAX.	
Α	0.95	1.05	1.15	
A1	0.00	0.05	0.10	
A2	0.95	1.00	1.05	
А3		0.15 REI	F	
b	0.27	0.32	0.37	
С	0.12	0.17	0.22	
c2	0.12	0.17	0.22	
D1	2.50	2.60	2.70	
D2	1.82	1.92	2.02	
D3	1.46	1.56	1.66	
D4	0.20	0.25	0.30	
Е	3.20	3.30	3.40	
E1	3.00	3.10	3.20	
E2	2.15	2.25	2.35	
е	0.65 BSC			
Н	3.20	3.30	3.40	
L	0.25	0.37	0.50	
L1	0.48	0.58	0.68	
L2	0.35	0.45	0.55	
Q	0.45	0.50	0.55	
θ	0°	4°	8°	

#### **GENERIC MARKING DIAGRAM\***

XXXXX XXXXX **AWLYW** 

XXXX = Specific Device Code = Assembly Location

WL = Wafer Lot = Year W = Work Week

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON05544H	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	LFPAK8 3.3x3.3, 0.65P		PAGE 1 OF 1	

onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries, onsemi reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

#### ADDITIONAL INFORMATION

**TECHNICAL PUBLICATIONS:** 

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales